

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	6	(voltage same flatten\$3) same (clip\$3 near circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/23 10:28
L2	3	(voltage same flatten\$3) same ((substrate or wafer) near (bias near power))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/23 10:14
L3	8	watanabe-seiichi.in. and (voltage same flatten\$3)	US-PGPUB; USPAT	OR	OFF	2005/10/23 10:22
L4	5	tamura-hitoshi.in. and (voltage same flatten\$3)	US-PGPUB; USPAT	OR	OFF	2005/10/23 10:23
L5	8	yasui-naoki.in. and (voltage same flatten\$3)	US-PGPUB; USPAT	OR	OFF	2005/10/23 10:23
L6	12	(bias\$3 near power) same (clip\$3 near circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/23 10:28